BAT54VV

Schottky barrier triple diode in ultra small SOT666 package

Rev. 02 — 15 January 2010

Product data sheet

1. Product profile

1.1 General description

Planar Schottky barrier triple diode with an integrated guard ring for stress protection. Three electrically isolated Schottky barrier diodes, encapsulated in a SOT666 ultra small SMD plastic package.

1.2 Features

- Low forward voltage
- Ultra small SMD plastic package
- Low capacitance
- Flat leads: excellent coplanarity and improved thermal behavior

1.3 Applications

- Ultra high-speed switching
- Voltage clamping
- Line termination
- Inverse-polarity protection

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_R	continuous reverse voltage		-	-	30	V
I _F	continuous forward current		-	-	200	mA

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Symbol
1	anode (diode 1)		
2	anode (diode 2)	6 5 4	6 5 4
3	anode (diode 3)		
4	cathode (diode 3)		1 2 3
5	cathode (diode 2)	0	sym046
6	cathode (diode 1)	13 SOT666	





2 of 9

Schottky barrier triple diode in ultra small SOT666 package

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BAT54VV	-	plastic surface mounted package; 6 leads	SOT666

4. Marking

Table 4. Marking codes

Type number	Marking code
BAT54VV	C6

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per diode						
V_R	continuous reverse voltage			-	30	V
I _F	continuous forward current			-	200	mA
I _{FRM}	repetitive peak forward current	$t_p \le 1 \text{ s; } \delta \le 0.5$		-	300	mA
I _{FSM}	non-repetitive peak forward current	$t_{p} < 10 \text{ ms}$		-	600	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	[1][2]	-	170	mW
Tj	junction temperature			-	125	°C
T _{amb}	ambient temperature			-65	+125	°C
T _{stg}	storage temperature			-65	+150	°C

^[1] Device mounted on a FR4 printed-circuit board, single-sided copper, tin-plated and standard footprint.

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1][2]	-	590	K/W

^[1] Refer to SOT666 standard mounting conditions.

BAT54VV_2 © NXP B.V. 2010. All rights reserved.

^[2] Single diode loaded.

^[2] Reflow soldering is the only recommended soldering method.

NXP Semiconductors

BAT54V

Schottky barrier triple diode in ultra small SOT666 package

7. Characteristics

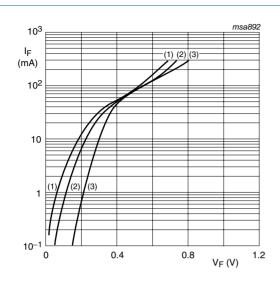
Table 7. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

	<u> </u>					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
V _F	forward voltage	see <u>Figure 1</u> ;	<u>[1]</u>			
		$I_F = 0.1 \text{ mA}$	-	-	240	mV
		$I_F = 1 \text{ mA}$	-	-	320	mV
		I _F = 10 mA	-	-	400	mV
		$I_F = 30 \text{ mA}$	-	-	500	mV
		I _F = 100 mA	-	-	800	mV
I _R	reverse current	V _R = 25 V; see Figure 2	-	-	2	μΑ
C _d	diode capacitance	$V_R = 1 \text{ V; } f = 1 \text{ MHz;}$ see Figure 3	-	-	10	pF

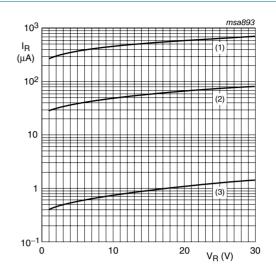
^[1] Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$





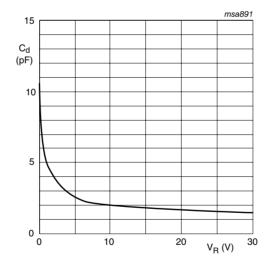
- (1) $T_{amb} = 125 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values



- (1) $T_{amb} = 125 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$

Fig 2. Reverse current as a function of reverse voltage; typical values



 $T_{amb} = 25 \, ^{\circ}C; f = 1 \, MHz$

Fig 3. Diode capacitance as a function of reverse voltage; typical values

4 of 9



8. Package outline

Plastic surface-mounted package; 6 leads

SOT666

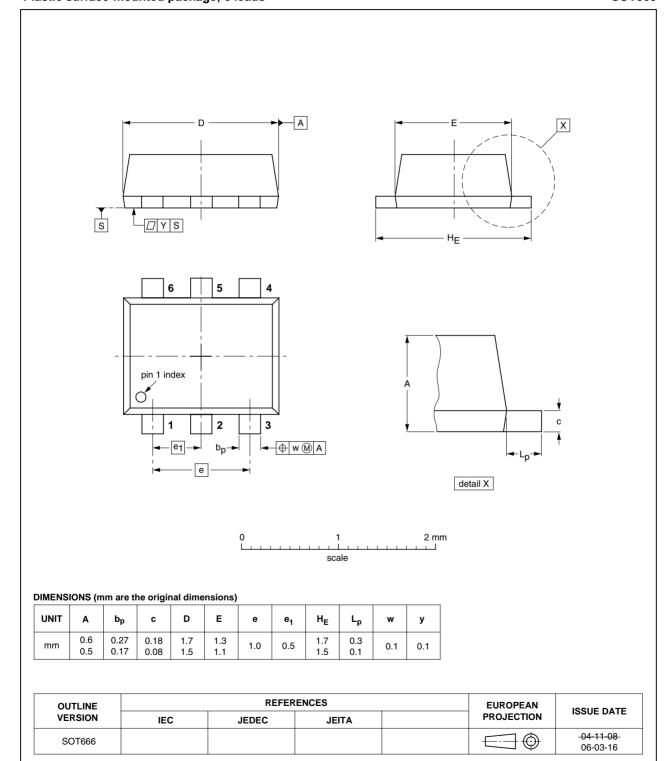


Fig 4. Package outline SOT666.



9. Packing information

Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity
			4000
BAT54VV	SOT666	4 mm pitch, 8 mm tape and reel	-115

^[1] For further information and the availability of packing methods, see Section 12.

10. Revision history

Table 9. **Revision history**

Product data sheet

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAT54VV_2	20100115	Product data sheet	-	BAT54VV_1
Modifications:		eet was changed to reflect w legal definitions and disc		
	 Table 2 "Pini 	ning": updated		
	Figure 4 "Pa	ckage outline SOT666.": up	odated	
BAT54VV_1	20040914	Product data sheet	-	-

7 of 9

NXP Semiconductors

BAT54VV

Schottky barrier triple diode in ultra small SOT666 package

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

11.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

11.3 Disclaimers

General — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in medical, military, aircraft, space or life support equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental

damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) may cause permanent damage to the device. Limiting values are stress ratings only and operation of the device at these or any other conditions above those given in the Characteristics sections of this document is not implied. Exposure to limiting values for extended periods may affect device reliability.

Terms and conditions of sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, including those pertaining to warranty, intellectual property rights infringement and limitation of liability, unless explicitly otherwise agreed to in writing by NXP Semiconductors. In case of any inconsistency or conflict between information in this document and such terms and conditions, the latter will prevail.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from national authorities.

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

11.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

8 of 9

12. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

NXP Semiconductors



Schottky barrier triple diode in ultra small SOT666 package

13. Contents

1	Product profile
1.1	General description 1
1.2	Features
1.3	Applications
1.4	Quick reference data 1
2	Pinning information 1
3	Ordering information 2
4	Marking 2
5	Limiting values 2
6	Thermal characteristics 2
7	Characteristics
8	Package outline 5
9	Packing information 6
10	Revision history 7
11	Legal information 8
11.1	Data sheet status 8
11.2	Definitions 8
11.3	Disclaimers
11.4	Trademarks 8
12	Contact information 8
13	Contents

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.







founded by

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

NXP:

BAT54VV,115